

**Amendments to the Specification :**

**Please rewrite the paragraph on page 1, lines 3-4 as follows:**

**Cross-Reference to Related Application**

This application claims the benefit of Japanese Application 2002-268765, filed September 13, 20032002, the entirety of which is incorporated herein by reference.

**Please rewrite the section heading on page 5, line 15 as follows:**

**DETAILED DESCRIPTION OF ~~PREFERRED EMBODIMENT~~THE  
INVENTION**

**Please rewrite the paragraph on page 16, lines 4-10 as follows:**

In the aforementioned method for producing a semiconductive glaze product of the present invention, while raw materials—which ~~contains~~ contain large particles—are mixed together, the particle size of raw materials is reduced through milling so that the raw materials have a predetermined particle size. However, when raw materials which have been reduced in size beforehand are available, needless to say, a desired glaze product can be produced merely by mixing the raw materials.